

产品规格书

Specifcation of products

产品名称:可控硅模块

产品型号: MFC200A-Y04

浙江世菱半导体有限公司
ZHEJIANG SHILING SEMICONDUCTOR CO.,LTD.

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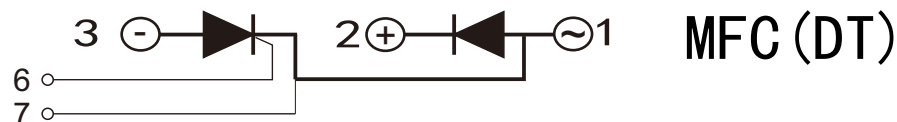
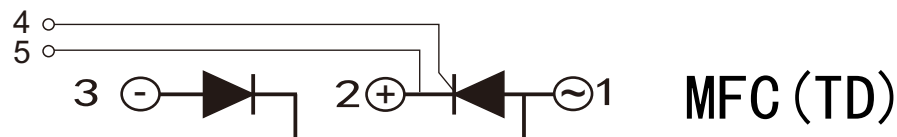
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拟制	审核	核准
林益龙	曹剑龙	宗瑞

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)				UNIT
				Min	Type	Max	
I _{T(AV)}	Mean on-state current	180° half sine wave 50Hz Single side cooled, T _C =85°C	125			200	A
I _{T(RMS)}	RMS on-state current	Single side cooled, T _C =85°C	125			314	A
V _{DRM} V _{RRM}	Repetitive peak off-state voltage Repetitive peak reverse voltage	V _{DRM} &V _{RRM} tp=10ms V _{DSM} &V _{RSM} = V _{DRM} &V _{RRM} +200V respectively	125		1600	1800	V
I _{DRM} I _{RRM}	Repetitive peak current	at V _{DRM} at V _{RRM}	125			30	mA
I _{TSM}	Surge on-state current	10ms half sine wave	125			8.00	KA
I ² t	I ² T for fusing coordination	V _R =60%V _{RRM}				320	A ² s*10 ³
V _{TO}	Threshold voltage		125			0.85	V
r _T	On-state slop resistance					1.45	mΩ
V _{TM}	Peak on-state voltage	I _{TM} =600A	25			1.50	V
V _{FM}	Peak on-state voltage	I _{FM} =600A	25			1.30	V
dv/dt	Critical rate of rise of off-state voltage	V _{DM} =67%V _{DRM}	125			1000	V/μs
di/dt	Critical rate of rise of on-state current	From 67%V _{DRM} To 750A, Gate source 1.5A t _r ≤ 0.5 μs Repetitive	125			200	A/μs
I _{GT}	Gate trigger current	V _A =12V, I _A =1A	25	30		180	mA
V _{GT}	Gate trigger voltage			1.0		2.5	V
I _H	Holding current			20		100	mA
V _{GD}	Non-trigger gate voltage	At 67%V _{DRM}	125			0.2	V
R _{th(j-c)}	Thermal resistance Junction to heatsink	At 180° sine Single side cooled				0.120	°C /W
V _{iso}	Isolation voltage	50Hz, RMS, t=1min, I _{iso} : 1mA (MAX)		2500			V
F _m	Thermal connection torque(M8)				5.0		N.m
	Mounting torque(M6)				5.0		N.m
T _{stg}	Stored temperature			-40		150	°C
W _t	Weight				900		g
Outline							

OUTLINE DRAWING & CIRCUIT DIAGRAM



Rating and Characteristic

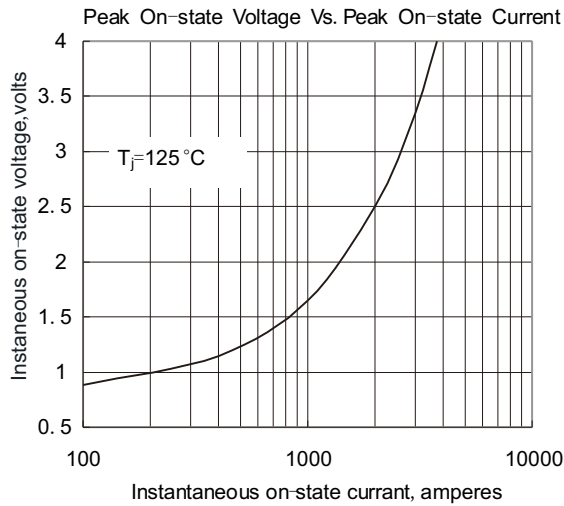


Fig.1

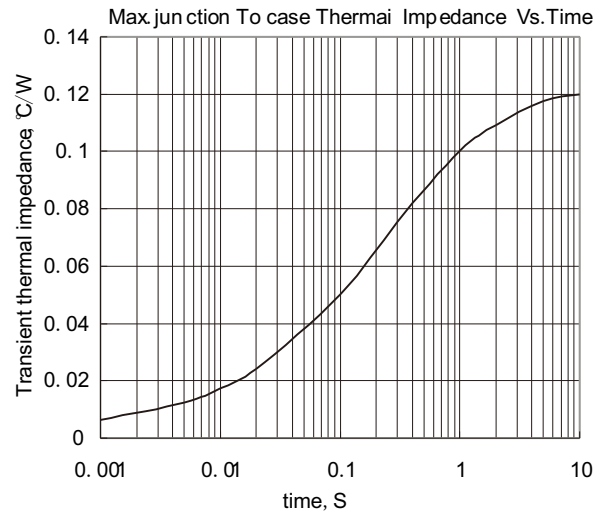


Fig.2

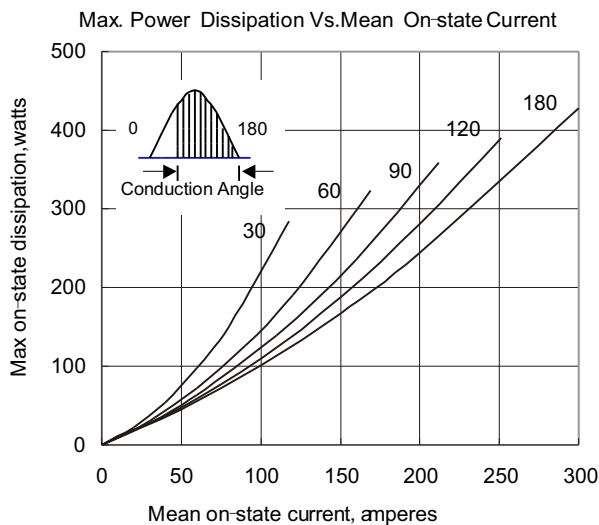


Fig.3

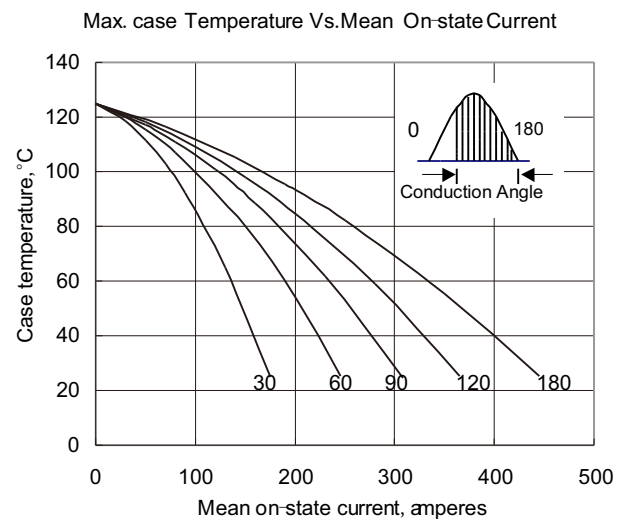


Fig.4

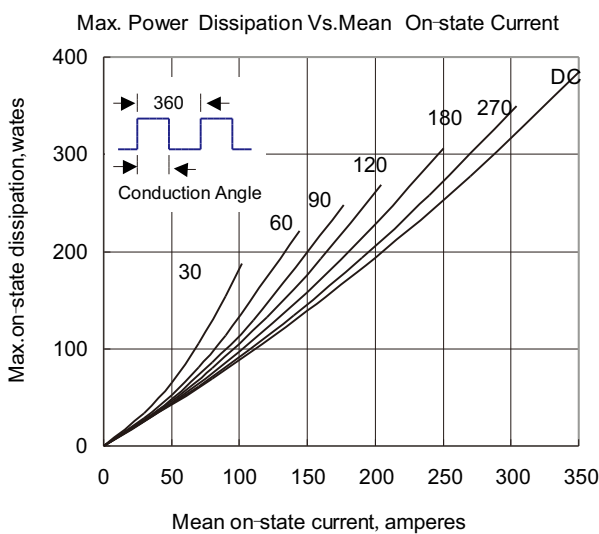


Fig.5

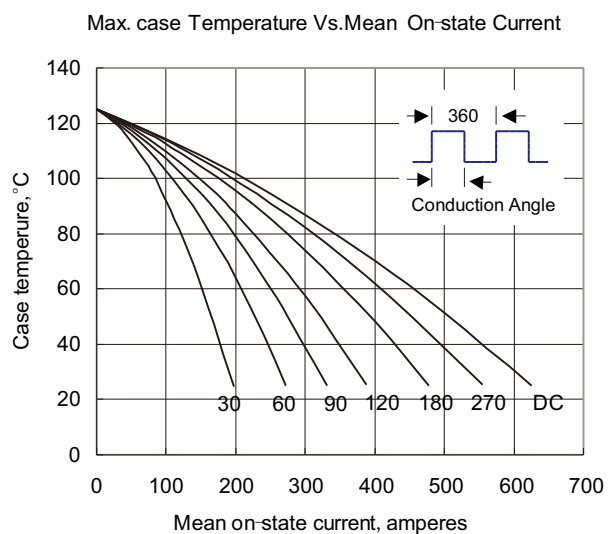


Fig.6

Rating and Characteristic

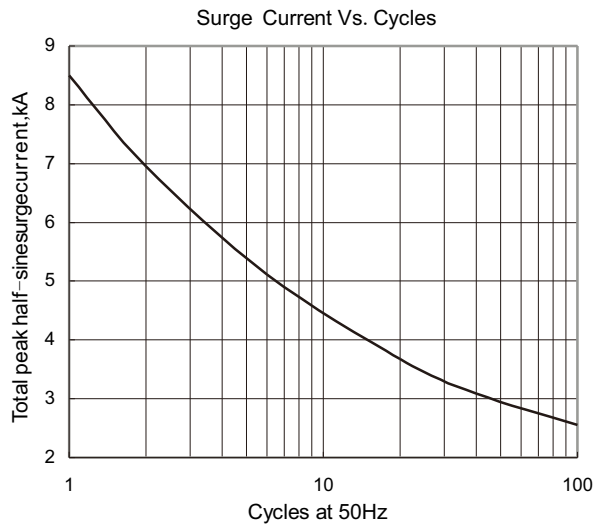


Fig. 7

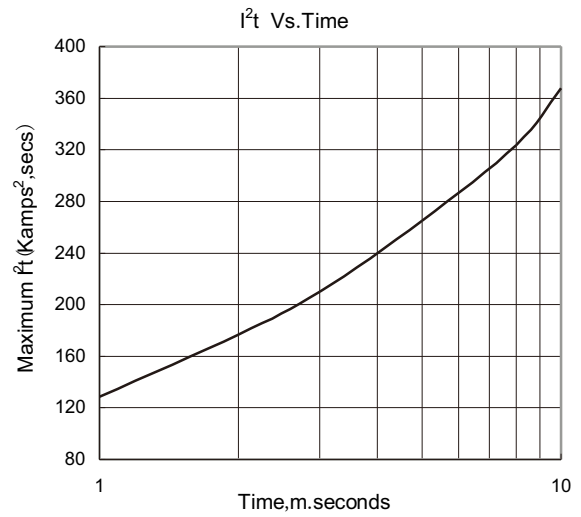


Fig. 8

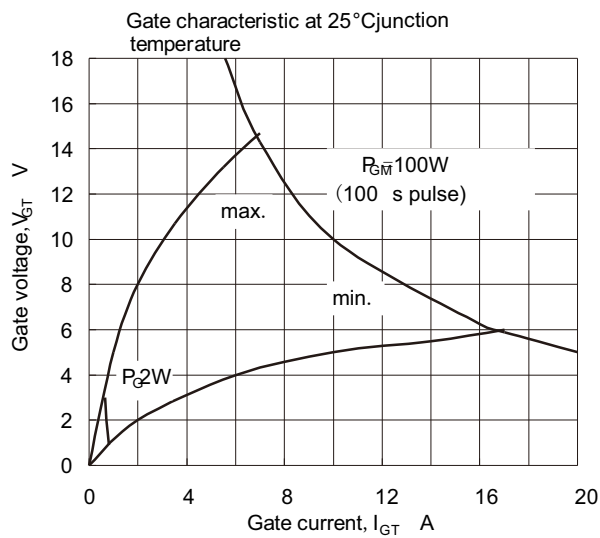


Fig. 9

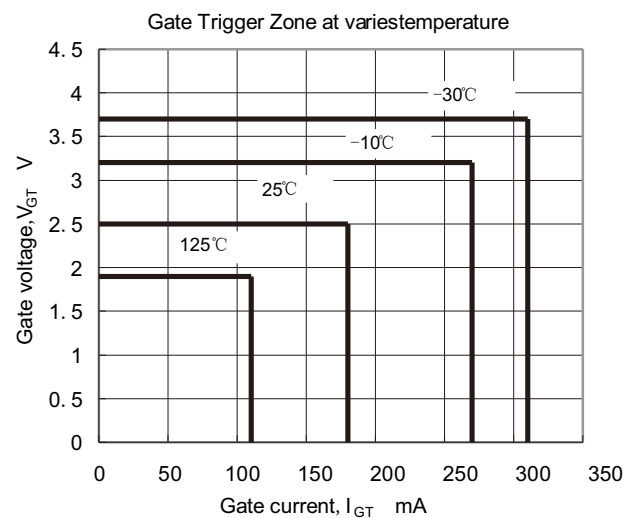


Fig. 10

Outside Dimension

